TC913A/TC913B

Dual Auto-Zeroed Operational Amplifiers

Features:

- First Monolithic Dual Auto-Zeroed Operational Amplifier
- Chopper Amplifier Performance Without External Capacitors:
  - V_{OS}: 15 µV Max.
  - V_{OS}: Drift; 0.15 µV/°C Max.
  - Saves Cost of External Capacitors
- SOIC Packages Available
- High DC Gain; 120dB
- Low Supply Current; 650 µA
- Low Input Voltage Noise:
  - 0.65 μV_{P-P} (0.1 Hz to 10 Hz)
- Wide Common Mode Voltage Range:
  - V_{SS} to V_{DD} - 2V
- High Common Mode Rejection; 116dB
- Dual or Single Supply Operation:
  - ±3.3V to ±8.3V
  - +6.5V to +16V
- Excellent AC Operating Characteristics:
  - Slew Rate; 2.5V/µsec
  - Unity-Gain Bandwidth; 1.5 MHz
- Pin Compatible with LM358, OP-14, MC1458, ICL7621, TL082, TLC322

Applications:

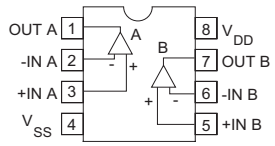
- Instrumentation
- Medical Instrumentation
- Embedded Control
- Temperature Sensor Amplifier
- Strain Gage Amplifier

Device Selection Table

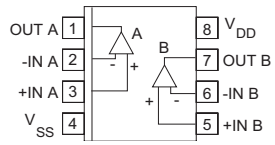
Part Number	Package	Temp. Range	Offset Voltage
TC913ACOA	8-Pin SOIC	0°C to +70°C	15 µV
TC913ACPA	8-Pin PDIP	0°C to +70°C	15 µV
TC913BCOA	8-Pin SOIC	0°C to +70°C	30 µV
TC913BCPA	8-Pin PDIP	0°C to +70°C	30 µV

Package Type

PDIP
TC913ACPA
TC913BCPA



SOIC
TC913ACOA
TC913BCOA



General Description:

The TC913 is the world's first complete monolithic, dual auto-zeroed operational amplifier. The TC913 sets a new standard for low-power, precision dual-operational amplifiers. Chopper-stabilized or auto-zeroed amplifiers offer low offset voltage errors by periodically sampling offset error, and storing correction voltages on capacitors. Previous single amplifier designs required two user-supplied, external 0.1µF error storage correction capacitors — much too large for on-chip integration. The unique TC913 architecture requires smaller capacitors, making on-chip integration possible. Microvolt offset levels are achieved and **external capacitors are not required.**

The TC913 system benefits are apparent when contrasted with a TC7650 chopper amplifier circuit implementation. A single TC913 replaces two TC7650's and four capacitors. Five components and assembly steps are eliminated.

The TC913 pinout matches many popular dual-operational amplifiers: OP-04, TLC322, LM358, and ICL7621 are typical examples. In many applications, operating from dual 5V power supplies or single supplies, the TC913 offers superior electrical performance, and can be a functional drop-in replacement; printed circuit board rework is not necessary. The TC913's low offset voltage error eliminates offset voltage trim potentiometers often needed with bipolar and low accuracy CMOS operational amplifiers.

The TC913 takes full advantage of Microchip's proprietary CMOS technology. Unity gain bandwidth is 1.5 MHz and slew rate is 2.5V/µsec.

1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings*

Total Supply Voltage (V_{DD} to V_{SS}) ..... +18V

Input Voltage ..... (V_{DD} +0.3V) to (V_{SS} -0.3V)

Current Into Any Pin..... 10 mA
While Operating ..... 100 µA

Package Power Dissipation (T_A – 70°C)
Plastic DIP ..... 730 mW
Plastic SOIC ..... 470 mW

Operating Temperature Range
C Device ..... 0°C to +70°C

Storage Temperature Range..... -65°C to +150°C

*Stresses above those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions above those indicated in the operation sections of the specifications is not implied. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability.

TC913A AND TC913B ELECTRICAL SPECIFICATIONS

Electrical Characteristics: V_S = ±5V, T_A = +25°C, unless otherwise indicated.

			TC913A			TC913B			
Symbol	**Parameter**	**Min**	**Typ**	**Max**	**Min**	**Typ**	**Max**	**Unit**	**Test Conditions**
V_{OS}	Input Offset Voltage	—	5	15	—	15	30	µV	T_A = +25°C
TCV_{OS}	Average Temp. Coefficient of Input Offset Voltage	— —	0.05 0.05	0.15 0.15	— —	0.1 0.1	0.25 0.25	µV/°C µV/°C	0°C ≤ T_A ≤ +70°C -25°C ≤ T_A ≤ +85°C **(Note 1)**
I_B	Average Input Bias Current	— — —	— — —	90 3 4	— — —	— — —	120 4 6	pA nA nA	T_A = +25°C 0°C ≤ T_A ≤ +70°C -25°C ≤ T_A ≤ +85°
I_{OS}	Average Input Offset Current	— —	5 —	20 1	— —	10 —	40 1	pA nA	T_A = +25°C T_A = +85°C
e_N	Input Voltage Noise	— —	0.6 11	— —	— —	0.6 11	— —	μV_{P-P} μV_{P-P}	0.1 to 1 Hz, R_S ≤ 100Ω 0.1 to 10 Hz, R_S ≤ 100Ω
CMRR	Common Mode Rejection Ratio	110	116	—	100	110	—	dB	V_{SS} ≤ V_{CM} ≤ V_{DD} - 2.2
CMVR	Common Mode Voltage Range	V_{SS}	—	V_{DD} - 2	V_{SS}	—	V_{DD} - 2	V	
A_{OL}	Open-Loop Voltage Gain	115	120	—	110	120	—	dB	R_L = 10 kΩ, V_{OUT} = ±4V
V_{OUT}	Output Voltage Swing	V_{SS} + 0.3	—	V_{DD} - 0.9	V_{SS} + 0.3	—	V_{DD} -0.9	V	R_L = 10 kΩ
BW	Closed Loop Bandwidth	—	1.5	—	—	1.5	—	MHz	Closed Loop Gain = +1
SR	Slew Rate	—	2.5	—	—	2.5	—	V/µsec	R_L = 10 kΩ, C_L = 50 pF
PSRR	Power Supply Rejection Ratio	110	—	—	100	—	—	dB	±3.3V to ±5.5V
V_S	Operating Supply Voltage Range	±3.5 7.0	— —	±8.3 16	±3.5 7.0	— —	±8.3 16	V V	Split Supply Single Supply
I_S	Quiescent Supply Current	—	0.65	0.85	—	—	1.1	mA	V_S = ±5V

Note 1: Characterized; not 100% tested.

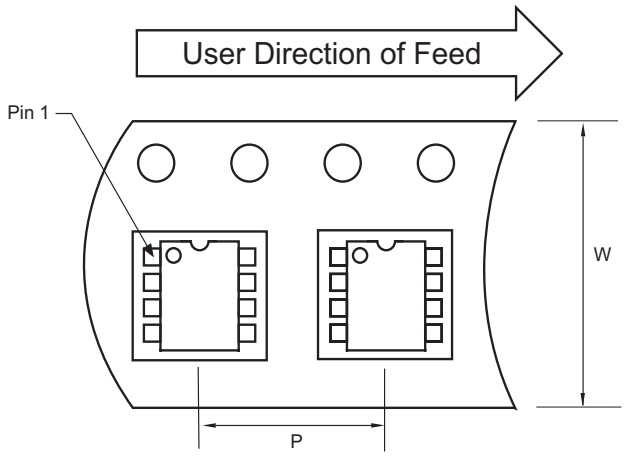
5.0 PACKAGING INFORMATION

5.1 Package Marking Information

Package marking data not available at this time.

5.2 Taping Form

Component Taping Orientation for 8-Pin SOIC (Narrow) Devices



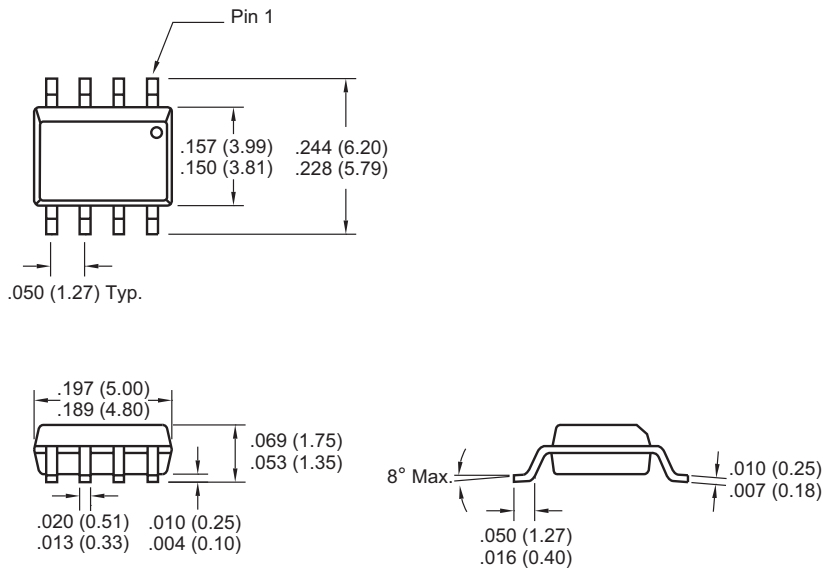
Standard Reel Component Orientation
for 713 Suffix Device

Carrier Tape, Number of Components Per Reel and Reel Size

Package	Carrier Width (W)	Pitch (P)	Part Per Full Reel	Reel Size
8-Pin SOIC (N)	12 mm	8 mm	2500	13 in

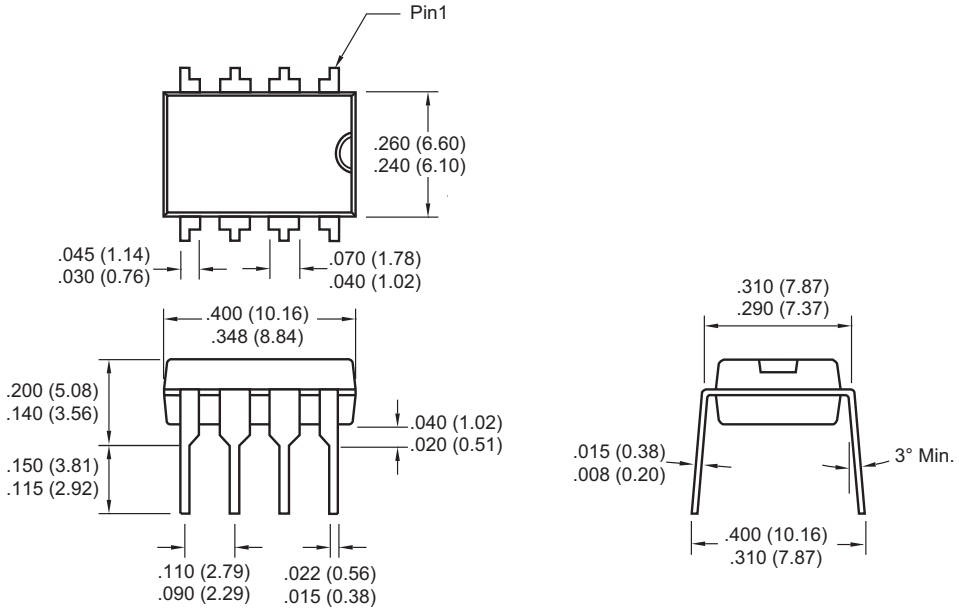
5.3 Package Dimensions

8-Pin SOIC



Dimensions: inches (mm)

8-Pin Plastic DIP



Dimensions: inches (mm)